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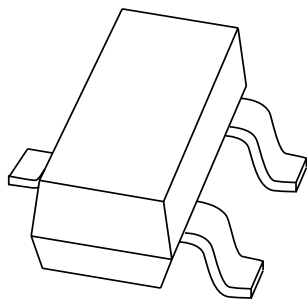
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If you have any questions related to the data sheet, please contact our nearest sales office via e-mail or telephone (details via **salesaddresses@nexperia.com**). Thank you for your cooperation and understanding,

Kind regards,

Team Nexperia

DATA SHEET



PLVA6xxA series Low-voltage avalanche regulator diodes

Product data sheet
Supersedes data of 1999 May 25

2004 Jan 14

Low-voltage avalanche regulator diodes

PLVA6xxA series

FEATURES

- Very low dynamic impedance at low currents: approximately $\frac{1}{20}$ of conventional series
- Hard breakdown knee
- Low noise: approximately $\frac{1}{10}$ of conventional series
- Total power dissipation: max. 250 mW
- Small tolerances of V_Z
- Working voltage range: nominal 5.00 to 6.80 V
- Non-repetitive peak reverse power dissipation: maximal 30 W.

APPLICATIONS

- Low current, low power, low noise applications
- CMOS RAM back-up circuits
- Voltage stabilizers
- Voltage limiters
- Smoke detector relays.

DESCRIPTION

High performance voltage regulator diodes in small SOT23 plastic SMD packages.

The series consists of PLVA650A to PLVA668A.

MARKING

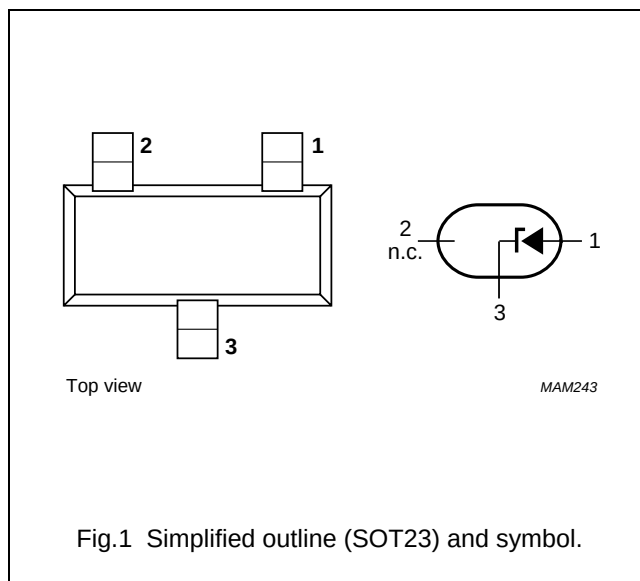
TYPE NUMBER	MARKING CODE ⁽¹⁾
PLVA650A	*9A
PLVA653A	*9B
PLVA656A	*9C
PLVA659A	*9D
PLVA662A	*9E
PLVA665A	*9F
PLVA668A	*9G

Note

1. * = p: Made in Hong Kong.
* = t: Made in Malaysia.
* = W: Made in China.

PINNING

PIN	DESCRIPTION
1	anode
2	not connected
3	cathode



Low-voltage avalanche regulator diodes

PLVA6xxA series

ORDERING INFORMATION

TYPE NUMBER	PACKAGE		
	NAME	DESCRIPTION	VERSION
PLVA6xxA	–	plastic surface mounted package; 3 leads	SOT23

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I_F	continuous forward current		–	250	mA
I_{ZRM}	repetitive peak working current	$t_p = 100 \mu s$; $\delta = 10\%$	–	250	mA
P_{ZSM}	non-repetitive peak reverse power dissipation	$t_p = 100 \mu s$; $T_j = 150^\circ C$	–	30	W
P_{tot}	total power dissipation	$T_{amb} = 25^\circ C$; note 1	–	250	mW
T_{stg}	storage temperature		–65	+150	$^\circ C$
T_j	junction temperature		–	150	$^\circ C$

Note

1. Device mounted on an FR4 printed circuit-board.

Low-voltage avalanche regulator diodes

PLVA6xxA series

ELECTRICAL CHARACTERISTICST_j = 25 °C; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _F	forward voltage	I _F = 10 mA	—	—	0.9	V
V _Z	working voltage PLVA650A PLVA653A PLVA656A PLVA659A PLVA662A PLVA665A PLVA668A	I _Z = 250 µA	4.80 5.10 5.40 5.70 6.00 6.30 6.60	5.00 5.30 5.60 5.90 6.20 6.50 6.80	5.20 5.50 5.80 6.10 6.40 6.70 7.00	V V V V V V V
V _Z	working voltage PLVA650A PLVA653A PLVA656A PLVA659A PLVA662A PLVA665A PLVA668A	I _Z = 10 µA	— — — — — — —	4.30 5.20 5.51 5.85 6.19 6.49 6.80	— — — — — — —	V V V V V V V
R _Z	dynamic resistance PLVA650A PLVA653A PLVA656A to PLVA668A	1 kHz superimposed; I _{ZAC} is 10% of I _{ZDC} ; I _Z = 250 µA	— — —	— — —	700 250 100	Ω Ω Ω
S _Z	temperature coefficient PLVA650A PLVA653A PLVA656A PLVA659A PLVA662A PLVA665A PLVA668A	I _Z = 250 µA	— — — — — — —	0.20 1.60 1.90 2.40 2.65 2.90 3.40	— — — — — — —	mV/K mV/K mV/K mV/K mV/K mV/K mV/K
I _R	reverse current PLVA650A PLVA653A PLVA656A PLVA659A PLVA662A PLVA665A PLVA668A	V _R = 80% V _Z nominal	— — — — — — —	— — — — — — —	20000 5000 1000 500 100 50 10	nA nA nA nA nA nA nA

Low-voltage avalanche regulator diodes

PLVA6xxA series

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_R	reverse current	$V_R = 50\% V_Z$ nominal				
	PLVA650A		—	34	—	nA
	PLVA653A		—	22	—	nA
	PLVA656A		—	1.1	—	nA
	PLVA659A		—	0.9	—	nA
	PLVA662A		—	0.9	—	nA
	PLVA665A		—	0.9	—	nA
	PLVA668A		—	0.8	—	nA
I_R	reverse current	$V_R = 90\% V_Z$ nominal				
	PLVA650A		—	21	—	μA
	PLVA653A		—	3.5	—	μA
	PLVA656A		—	1.3	—	μA
	PLVA659A		—	1.0	—	μA
	PLVA662A		—	0.05	—	μA
	PLVA665A		—	0.04	—	μA
	PLVA668A		—	0.006	—	μA
ΔV_Z	line regulation					
	PLVA659A to PLVA668A	$I_{LO} = 10 \mu A; I_{HI} = 1 mA$	—	—	0.1	V
	PLVA656A	$I_{LO} = 50 \mu A; I_{HI} = 1 mA$	—	—	0.1	V
	PLVA650A	$I_{LO} = 100 \mu A; I_{HI} = 1 mA$	—	—	0.4	V
	PLVA653A	$I_{LO} = 100 \mu A; I_{HI} = 1 mA$	—	—	0.2	V
V_n	noise voltage density	$f = 1 kHz; B = 1 kHz; I_Z = 250 \mu A$	—	—	1.0	$\frac{\mu V}{\sqrt{Hz}}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th(j-tp)}$	thermal resistance from junction to tie-point		330	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Device mounted on an FR4 printed circuit-board.

Low-voltage avalanche regulator diodes

PLVA6xxA series

PACKAGE OUTLINE

Plastic surface-mounted package; 3 leads

SOT23

The diagrams illustrate the SOT23 package outline. The top view shows dimensions D (total width) and E (lead width). The side view shows dimensions A (total height), H_E (lead height), A₁ (lead thickness), Q (lead width at base), c (lead thickness at base), and L_p (lead length). The lead view shows dimensions e (lead pitch), e₁ (lead thickness), b_p (lead width), and 1, 2, 3 (lead positions). A scale bar indicates 0 to 2 mm.

DIMENSIONS (mm are the original dimensions)

UNIT	A	A ₁ max.	b _p	c	D	E	e	e ₁	H _E	L _p	Q	v	w
mm	1.1 0.9	0.1	0.48 0.38	0.15 0.09	3.0 2.8	1.4 1.2	1.9	0.95	2.5 2.1	0.45 0.15	0.55 0.45	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT23		TO-236AB				04-11-04 06-03-16

Low-voltage avalanche regulator diodes

PLVA6xxA series

DATA SHEET STATUS

DOCUMENT STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

Notes

1. Please consult the most recently issued document before initiating or completing a design.
2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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NXP Semiconductors

Customer notification

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

Contact information

For additional information please visit: <http://www.nxp.com>

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Printed in The Netherlands

R76/03/pp8

Date of release: 2004 Jan 14

Document order number: 9397 750 12445

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